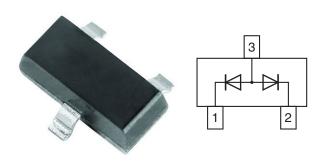


## Vishay Semiconductors

# **Small Signal Switching Diode, Dual**



#### **FEATURES**

- Silicon epitaxial planar diode
- · Fast switching dual diode with common anode
- AEC-Q101 qualified available (part number on request)
- Base P/N-G3 green, commercial grade
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





RoHS

HALOGEN FREE GREEN (5-2008)

### **DESIGN SUPPORT TOOLS** click logo to get started



### **MECHANICAL DATA**

Case: SOT-23

Weight: approx. 8.1 mg
Packaging codes / options:

18/10K per 13" reel (8 mm tape), 10K(/box 08/3K per 7" reel (8 mm tape), 15K/box

| PARTS TABLE |                            |                       |              |               |  |
|-------------|----------------------------|-----------------------|--------------|---------------|--|
| PART        | ORDERING CODE              | CIRCUIT CONFIGURATION | TYPE MARKING | REMARKS       |  |
| BAW56-G     | BAW56-G3-08 or BAW56-G3-18 | Common anode          | JDG          | Tape and reel |  |

| <b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)     |                       |                  |       |      |  |
|--|-----------------------|------------------|-------|------|--|
| PARAMETER  | TEST CONDITION        | SYMBOL           | VALUE | UNIT |  |
| Repetitive peak reverse voltage<br>= working peak reverse voltage<br>= DC blocking voltage |                       | $V_R = V_{RRM}$  | 70    | V    |  |
| Forward continuous current   |                       | I <sub>F</sub>   | 250   | mA   |  |
|  | t <sub>p</sub> = 1 μs | I <sub>FSM</sub> | 2     | Α    |  |
| Non repetitive peak forward current  | t <sub>p</sub> = 1 ms | I <sub>FSM</sub> | 1     | Α    |  |
|  | t <sub>p</sub> = 1 s  | I <sub>FSM</sub> | 0.5   | Α    |  |
| Power dissipation (1)  |                       | P <sub>tot</sub> | 350   | mW   |  |

| THERMAL CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified) |                |                       |             |      |  |
|--|----------------|-----------------------|-------------|------|--|
| PARAMETER  | TEST CONDITION | SYMBOL                | VALUE       | UNIT |  |
| Thermal resistance junction to ambient air                                     |                | R <sub>thJA</sub> (1) | 430         | K/W  |  |
| Junction temperature   |                | Tj                    | 150         | °C   |  |
| Storage temperature range  |                | T <sub>stg</sub>      | -65 to +150 | °C   |  |
| Operating temperature range  |                | T <sub>op</sub>       | -55 to +150 | °C   |  |

#### Note

(1) Device on fiberglass substrate



# Vishay Semiconductors

| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                 |      |      |       |      |
|--|--|-----------------|------|------|-------|------|
| PARAMETER  | TEST CONDITION   | SYMBOL          | MIN. | TYP. | MAX.  | UNIT |
|  | I <sub>F</sub> = 1 mA  | V <sub>F</sub>  |      |      | 0.715 | V    |
| Forward voltage  | I <sub>F</sub> = 10 mA   | V <sub>F</sub>  |      |      | 0.855 | V    |
| Forward voltage  | $I_F = 50 \text{ mA}$  | V <sub>F</sub>  |      |      | 1     | V    |
|  | I <sub>F</sub> = 150 mA  | V <sub>F</sub>  |      |      | 1.25  | V    |
|  | V <sub>R</sub> = 70 V  | I <sub>R</sub>  |      |      | 2500  | nA   |
| Reverse current  | $V_R = 70 \text{ V}, T_j = 150 ^{\circ}\text{C}$               | I <sub>R</sub>  |      |      | 100   | μΑ   |
|  | V <sub>R</sub> = 25 V, T <sub>j</sub> = 150 °C                 | I <sub>R</sub>  |      |      | 30    | μA   |
| Diode capacitance  | $V_F = V_R = 0$ , $f = 1$ MHz                                  | C <sub>D</sub>  |      |      | 2     | pF   |
| Reverse recovery time  | $I_F$ =10 mA to $I_R$ =1 mA, $V_R$ = 6 V, $R_L$ = 100 $\Omega$ | t <sub>rr</sub> |      |      | 6     | ns   |

### **TYPICAL CHARACTERISTICS** ( $T_{amb} = 25$ °C, unless otherwise specified)

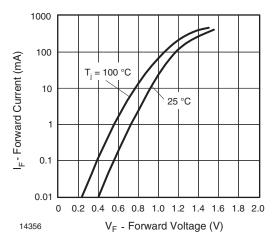


Fig. 1 - Forward Current vs. Forward Voltage

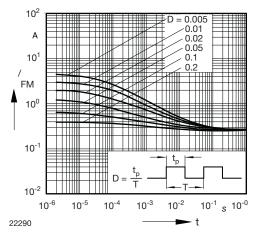
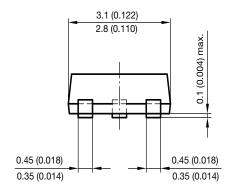
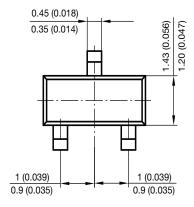


Fig. 2 - Peak Forward Current  $f_{fm} = f(t_p)$ 

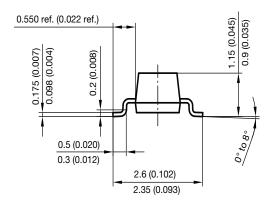
## Vishay Semiconductors

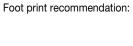
### PACKAGE DIMENSIONS in millimeters (inches): SOT-23

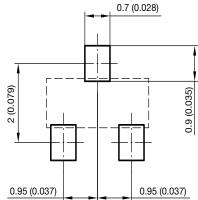




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